

COMPLEMENTARY MEDIUM-POWER HIGH VOLTAGE **POWER TRANSISTORS**

... designed for high-speed switching and linear amplifier application for high-voltage operational amplifiers, switching regulators, convertors, deflection stages and high fidelity amplifiers. FEATURES:

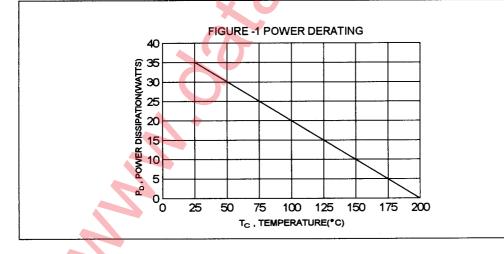
- * Continuous Collector Current $I_c = 2 A$ * Power Dissipation $P_D = 35 W @ T_c = 25^{\circ}C$ * $V_{CE(SAT)} = 0.75 V (Max.) @ I_c = 1.0 A, I_B = 125 mA$

MAXIMUM RATINGS

· · · · · · · · · · · · · · · · · · ·	T					
Characteristic	Symbol	2N3583 2N6420	2N3584 2N6421	2N3585 2N6422		Unit
Collector-Emitter Voltage	V _{CEO}	175	250	300	300	v
Collector-Base Voltage	V _{CBO}	250	375	500	500	v
Emitter-Base Voltage	V _{EBO}	6			V	
Collector Current-Continuous Peak	I _C	1.0 5.0			А	
Base Current	l _B	1.0			Α	
Total Power Dissipation @T _c =25°C Derate above 25°C	PD	35 0.2			w w/°c	
Operating and Storage Junction Temperature Range	T _J ,T _{STG}	-65 to +200				°C

THERMAL CHARACTERISTICS

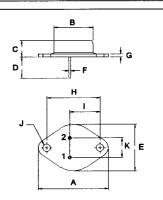
Characteristic	Symbol	Max	Unit
Thermal Resistance Junction to Case	Rejc	5.0	°C/W

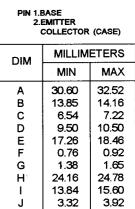


NPN	PNP
2N3583	2N6420
2N3584	2N6421
2N3585	2N6422
2N4240	2N6423
LINALAU	

1.0 AND 2.0 AMPERE POWER TRANSISTOR COMPLEMENTARY SILICON 175-300 VOLTS 35 WATTS







4.86

κ

5.34

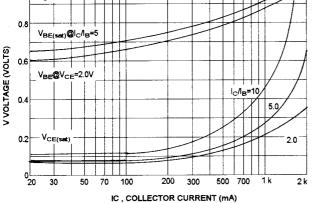
2N3583 thru 2N3585,2N4240 NPN / 2N6420 thru 2N6423 PNP

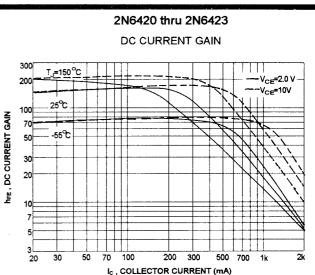
Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS				-	* ******
Collector - Emitter Sustaining Voltage (1)		V _{CEO(SUS)}			V
$(I_{c} = 200 \text{ mA}, I_{B} = 0) \text{ NPN}$	2N3583,2N6420	CEO(808)	175		
	2N3584,2N6421		250		
(I _c = 50 mA, I _B = 0) PNP	2N3585,2N6422		300		
•.	2N4240,2N6423		300		
Collector Cutoff Current		I _{CEO}			mA
(V _{CE} = 150 V, I _B = 0)	2N3583,2N6420	020		.10	
	2N3584,2N6421			5.0	
	2N3585,2N6422			5.0	
	2N4240,2N6423			5.0	
Collector Cutoff Current		ICEX			mA
(V _{CE} = 225 V, V _{BE(off)} = 1.5 V)	2N3583,2N6420	UEA		1.0	
$(V_{ce} = 340 \text{ V}, V_{BE(cff)} = 1.5 \text{ V})$	2N3584,2N6421			1.0	
$(V_{CE} = 450 \text{ V}, V_{BE(off)} = 1.5 \text{ V})$	2N3585,2N6422			1.0	
	2N4240,2N6423			2.0	
$(V_{CE} = 225 V, V_{BE(off)} = 1.5 V, T_{C} = 150^{\circ}C)$	2N3583,2N6420			3.0	
$(V_{CE} = 300 \text{ V}, V_{BE(off)} = 1.5 \text{ V}, T_{C} = 150^{\circ}\text{C})$	2N3584,2N6421			3.0	
	2N3585,2N6422			3.0	
	2N4240,2N6423			5.0	
Emitter Cutoff Current		IEBO			mA
(V _{EB} = 6.0 V, I _C = 0)	2N3583,2N6420			5.0	
	2N3584,2N6421			0.5	
	2N3585,2N6422			0.5	
· · · · · · · · · · · · · · · · · · ·	2N4240,2N6423			0.5	
ON CHARACTERISTICS (1)					
DC Current Gain		hFE			
$(I_{c} = 0.1 \text{ A}, V_{cE} = 10 \text{ V})$	All devices		40		
$(I_{c} = 0.5 \text{ A}, V_{ce} = 10 \text{ V})$	2N3583,2N6420		40	200	
$(I_c = 0.75 \text{ A}, V_{ce} = 2.0 \text{ V})$	2N4240,2N6423		10	100	
$(I_c = 0.75 \text{ A}, V_{cE} = 10 \text{ V})$	2N4240,2N6423		30	150	
$(I_{c} = 1.0 \text{ A}, V_{ce} = 2.0 \text{ V})$	2N3584,2N6421		8.0	80	
(1 = 10 A V = 10 V)	2N3585,2N6422		8.0 10	80	
(I _c = 1.0 A , V _{cE} = 10 V)	2N3583,2N6420 2N3084,2N6421		25	100	
	2N3585,2N6422		25	100	
Collector - Emitter Saturation Voltage					v
$(I_{\rm C} = 0.75 {\rm A}, I_{\rm B} = 75 {\rm mA})$	2N4240,2N6423	V _{CE(sat)}		1.0	-
$(I_{c} = 1.0 \text{ A}, I_{B} = 125 \text{ mA})$	2N3583,2N6420			5.0	
	2N3584,2N6421			0.75	
	2N3585,2N6422			0.75	
Base - Emitter Saturation Voltage		V _{BE(sat)}			v
$(I_c = 0.75 \text{ A}, I_m = 75 \text{ mA})$	2N4240,2N6423	- BE(Sat)		1.8	
$(l_c = 1.0 \text{ A}, l_B = 100 \text{ mA})$	2N3584,2N6421			1.4	
	2N3585,2N6422			1.4	
Base - Emitter On Voltage		V			V
$(I_c = 1.0 \text{ A}, V_{ce} = 10 \text{ V})$	All devices	V _{BE(on)}		1.4	-

(1) Pulse Test: Pulse width = 300 us , Duty Cycle $\leq 2.0\%$

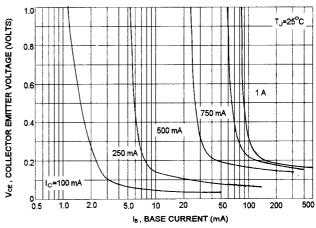
2N3585 thru 2N3585,2N4240 NPN / 2N6420 thru 2N6423 PNP

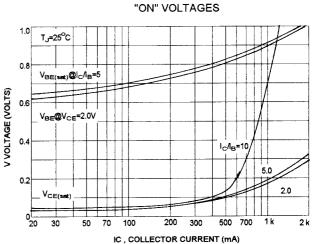
2N3583 thru 2N3585,2N4240 DC CURRENT GAIN 300 TTT -V_{CE}=2.0 V 200 --V_{CE}=10V Т 11 25°C 100 hre , DC CURRENT GAIN 70 50 -55°C 30 20 10 5 3∟ 20 30 50 70 100 200 300 500 700 1k 2k Ic , COLLECTOR CURRENT (mA) COLLECTOR SATURATION REGION 1.0 VCE , COLLECTOR EMITTER VOLTAGE (VOLTS) TJ=25℃ 0.8 0.6 1 A 750 mΑ 0.4 500 mA 250 mA 0.2 I_C=100 mA 0└___ 1.0 2.0 5.0 10 20 50 100 200 500 1 k IB, BASE CURRENT (mA) "ON" VOLTAGES 1.0 TJ=25℃







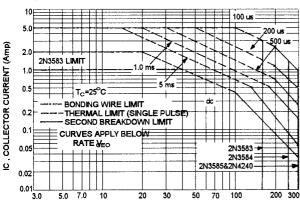




2N3583 thru 2N3585,2N4240 NPN/ 2N6420 thru 2N6423 PNP

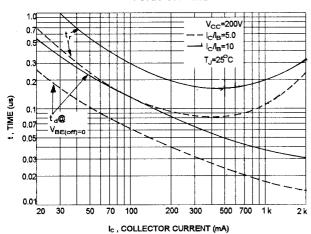
2N3583 thru 2N3585,2N4240

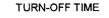
ACTIVE REGION SAFE OPERATING AREA

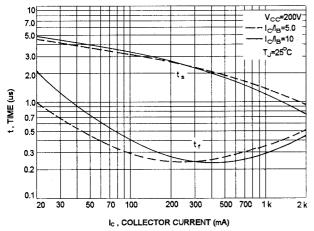


VCE , COLLECTOR EMITTER VOLTAGE (VOLTS)

TURN-ON TIME

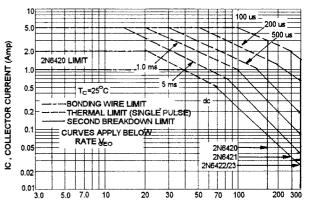






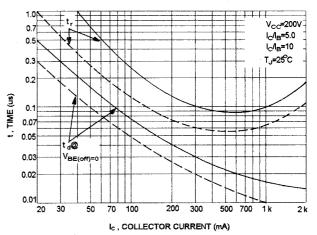
2N6420 thru 2N6423

ACTIVE REGION SAFE OPERATING AREA



VCE, COLLECTOR EMITTER VOLTAGE (VOLTS)

TURN-ON TIME



TURN-OFF TIME

